SCS230AE2HR

SiC Schottky Barrier Diode

Datasheet

V_R	650V
I_F	15A/30A*
Q_C	23nC

*(Per leg / Both legs)

●**AEC-Q101 Qualified**

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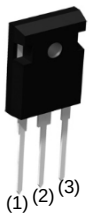


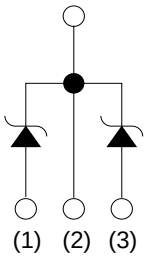
●**Features**

1) Shorter recovery time

2) Reduced temperature dependence

3) High-speed switching possible

●**Inner circuit**



(1) Anode
(2) Cathode
(3) Anode

●**Packaging specifications**

Type	Packaging	Tube
	Reel size (mm)	-
	Tape width (mm)	-
	Basic ordering unit (pcs)	30
	Packing code	C
	Marking	SCS230AE2

●**Construction**

Silicon carbide epitaxial planer Schottky Diode

●**Absolute maximum ratings** (Tj = 25°C)

Parameter	Symbol	Value	Unit
Reverse voltage (repetitive peak)	V_{RM}	650	V
Reverse voltage (DC)	V_R	650	V
Continuous forward current*7	I_F	15/30*1	A
Surge no repetitive forward current*7	I_{FSM}	55/110*2	A
		200/410*3	A
		43/87*4	A
Repetitive peak forward current*7	I_{FRM}	61/124*5	A
Total power disspation*7	P_D	110/230*6	W
Junction temperature	Tj	175	°C
Range of storage temperature	Tstg	−55 to +175	°C

*1 Tc=130°C/Tc=130°C *2 PW=8.3ms sinusoidal, Tj=25°C *3 PW=10μs square, Tj=25°C
*4 PW=8.3ms sinusoidal, Tj=150°C *5 Tc=100°C, Tj=150°C, Duty cycle=10%
*6 Tc=25°C *7 Per leg / Both legs

●Electrical characteristics (Tj = 25°C) (Per leg)

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
DC blocking voltage	V_{DC}	I_R =0.3mA	600	-	-	V
Forward voltage	V_F	I_F=15A,Tj=25°C	-	1.35	1.55	V
		I_F=15A,Tj=150°C	-	1.55	-	V
		I_F=15A,Tj=175°C	-	1.63	-	V
Reverse current	I_R	V_R=600V,Tj=25°C	-	3	300	μA
		V_R=600V,Tj=150°C	-	45	-	μA
		V_R=600V,Tj=175°C	-	105	-	μA
Total capacitance	C	V_R=1V,f=1MHz	-	550	-	pF
		V_R=600V,f=1MHz	-	56	-	pF
Total capacitive charge	Qc	V_R=400V,di/dt=350A/μs	-	23	-	nC
Switching time	tc	V_R=400V,di/dt=350A/μs	-	18	-	ns

●Thermal characteristics

Parameter	Symbol	Conditions	Values			Unit
			Min.	Typ.	Max.	
Thermal resistance	$R_{th(j-c)}$	Per Leg	-	1.1	1.3	°C/W
		Both Legs	-	0.55	0.63	°C/W

●Electrical characteristic curves

Fig.1 V_F - I_F Characteristics (Per leg)

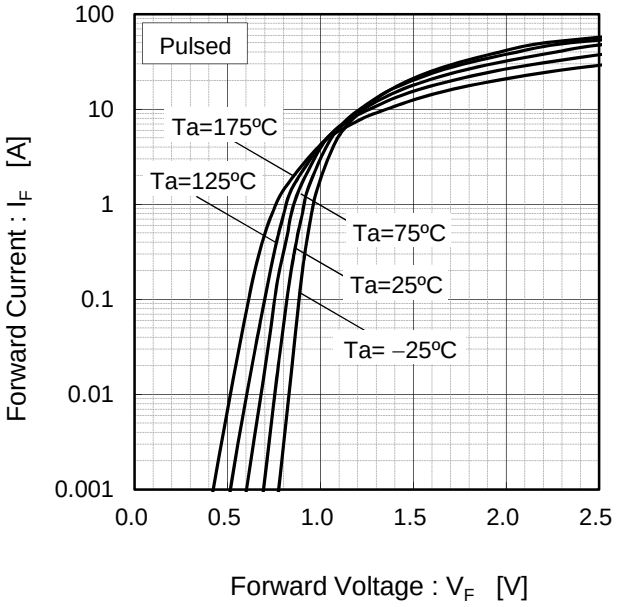


Fig.2 V_F - I_F Characteristics (Per leg)

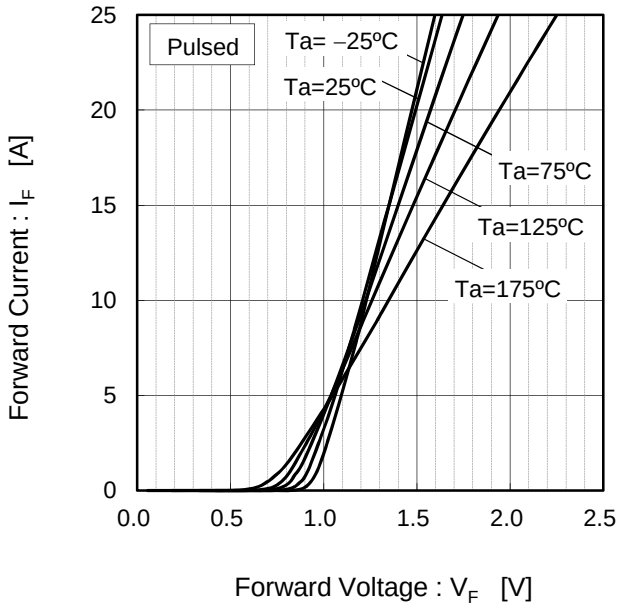


Fig.3 V_R - I_R Characteristics (Per leg)

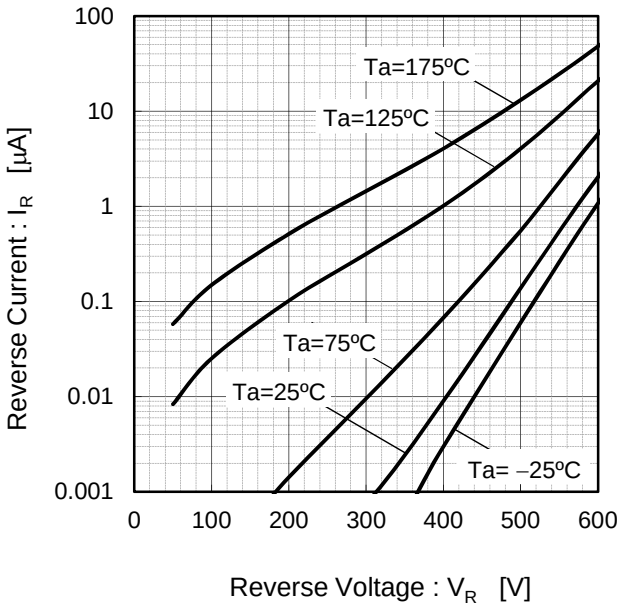
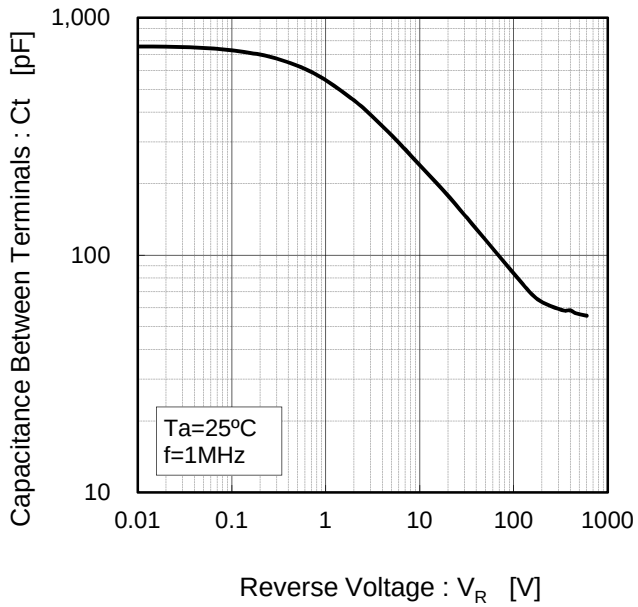


Fig.4 V_R-Ct Characteristics (Per leg)



●Electrical characteristic curves

Fig.5 Thermal Resistance vs. Pulse Width (Per leg)

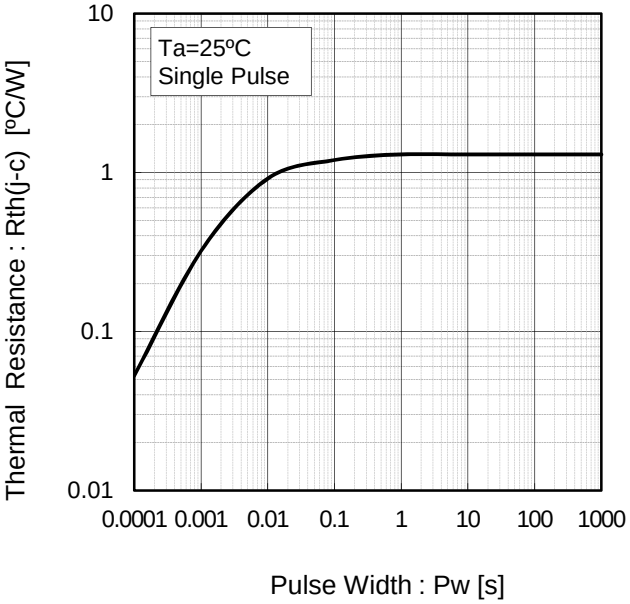


Fig.6 Power Dissipation (Per leg)

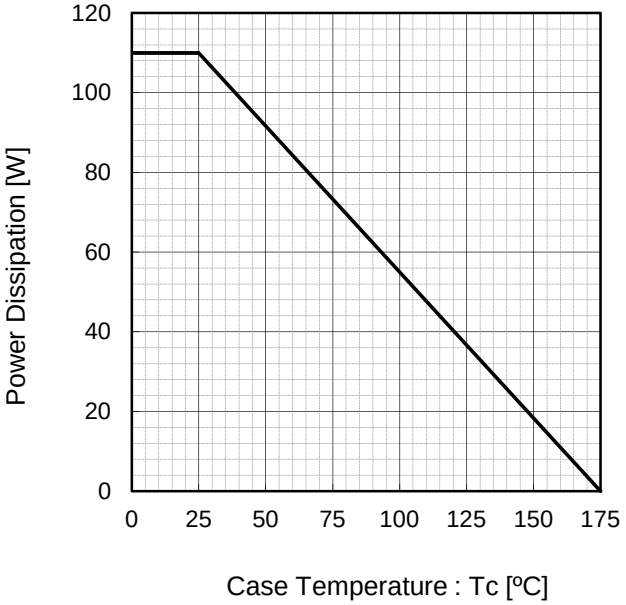


Fig.7 Derating Curve Ip-Tc (Per leg)

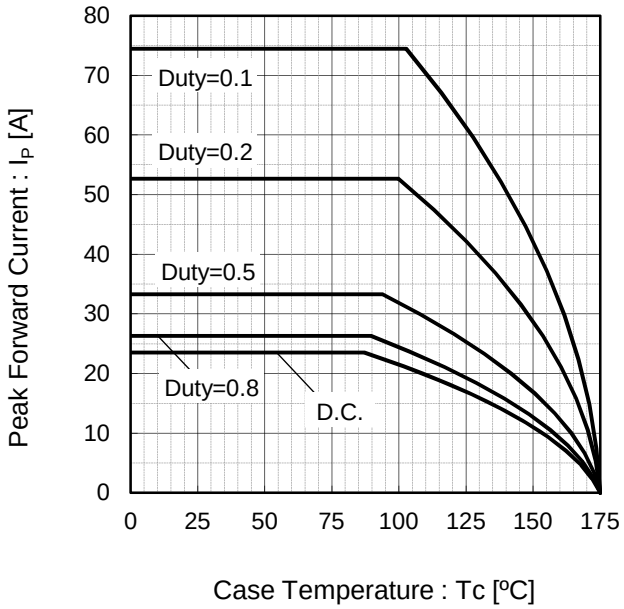
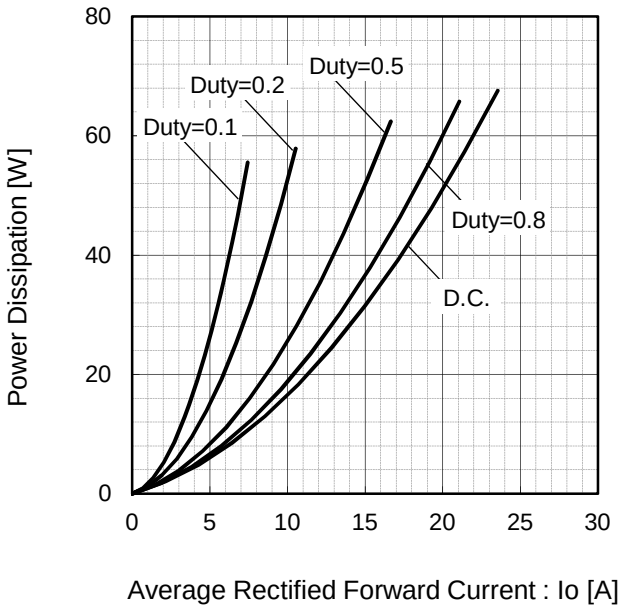


Fig.8 Io-Pf Characteristics (Per leg)



●**Dimensions** (Unit : mm)

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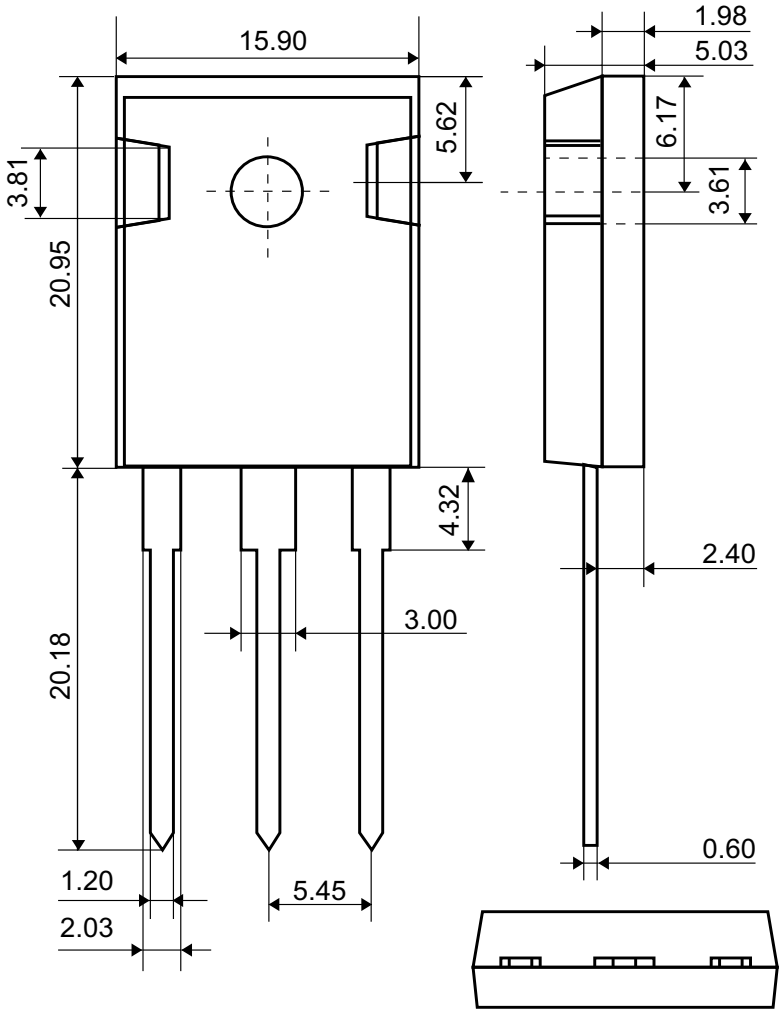

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